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Control No. PCN-18191

October 6, 2018

PRODUCT/PROCESS CHANGE NOTIFICATION

TYPE OF CHANGE:

Design

Manufacturing

Other

This notification is provided in accordance with Power Integrations policy of product/process change notification. If you have any questions or need further assistance, please contact your regional Power Integrations sales office.

DESCRIPTION OF CHANGE

- 1. Japan Semiconductor Corporation ("JSO"), Oita, Japan is added as an alternative 200mm wafer fab site for the products listed below.
- 2. There is neither change in technology nor the bill of materials.

REASON FOR CHANGE

Improve manufacturing flexibility and diversification of manufacturing sites.

PRODUCTS AFFECTED

Family	Part Numbers
InnoSwitch3-CE	INN3162C-Hxxx, INN3163C-Hxxx, INN3164C-Hxxx, INN3165C-Hxxx, INN3166C-Hxxx, INN3167C-
	Hxxx, INN3168C-Hxxx, SC1537C, SC1538C, SC1541C, SC1545C-HC13, SC1546C, SC1546C-HC15,
	SC1549C-HC30, SC1551C-HC26, SC1553C, SC1554C, SC1556C
InnoSwitch3-CP	INN3264C-Hxxx, INN3265C-Hxxx, INN3266C-Hxxx, INN3267C-Hxxx, INN3268C-Hxxx, INN3274C-
	Hxxx, INN3275C-Hxxx, INN3276C-Hxxx, INN3277C-Hxxx, SC1536C, SC1540C, SC1542C, SC1544C,
	SC1547C-HC17, SC1548C-HC32, SC1555C, SC1557C
InnoSwitch3-EP	INN3672C-Hxxx, INN3673C-Hxxx, INN3674C-Hxxx, INN3675C-Hxxx, INN3676C-Hxxx, INN3677C-
	Hxxx
LYTSwitch-6	LYT6063C, LYT6065C, LYT6067C, LYT6068C, LYT6073C, LYT6075C, LYT6077C

QUALIFICATION STATUS

See Appendix 1 for the qualification report.

EFFECT ON CUSTOMER

No adverse impact is expected in customers' applications. The product will be guaranteed to meet the datasheet limits.

EFFECTIVE DATE

January 7, 2019. This date is subject to change. Products fabricated at the current locations will continue to be shipped after the addition.

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SAMPLE AVAILABILITY

Samples will be available 8 weeks from the date of request. Please send requests for samples within two weeks after receipt of this notification to the local Power Integrations sales office. For manufacturers that request samples, an accommodation will be made in order to allow time of customer's qualification in a case-specific manner.



Appendix 1 Reliability Engineering Qualification Report Qualification Project: E175001

Project Title: Qualification of Japan Semiconductor Corporation, Oita, Japan ("JSO") as a wafer fabrication facility

Qual Summary:

Reliability testing was performed on InnoSwitch-3 products for wafer fabrication of the controller dice at Japan Semiconductor Corporation, Oita, Japan, also known as "JSO". All required reliability tests were completed on three qualification lots with passing results. Yield analysis and assembly-level testing were completed with acceptable results. Based on these results, "JSO" is a qualified wafer fabrication site for production of InnoSwitch-3 products.

Qualification Vehicles: INN3168C

Reliability Test Descriptions and Conditions

Test Name	Conditions	Reference Specification
DOPL (Dynamic Operating Life Test)	Tj=125°C, Vd _(peak) =520V, Vsupply = VBP	EIA/JESD22-A108-D
HTRB (High Temperature Reverse Bias Test)	Ta=150°C; Vd=520V, Vsupply = VBP	EIA/JESD22-A108-D
THBT (Temperature Humidity Bias Test)	85°C, 85% RH, Vd=30V, Vsupply = VBP	EIA/JESD22-A101-C
TMCL (Temperature Cycle, Air to Air)	-40°C to +125°C, air to air	EIA/JESD22-A104-E
HTSL (High Temperature Storage Life)	Ta=175°C; unbiased	EIA/JESD22-A103-D
HALT (Humidity Accelerated Life Test)	DOPL bias condition; Tj=115°C, 85% RH	Internal Standard
MSL3 Preconditioning	24-hr 150C bake → 40-hr 60°C, 60% RH soak → 3 passes 260C solder reflow	IPC/JEDEC J-STD-020E

DOPL (Dynamic Operating Life)

Product	Lot #	Qualification Project	Test Duration	No. Failures/Sample Size
INN3168C	M6P085B	E175001	MSL3 + 1000hr	0 / 47
INN3168C	M6P084B	E172011	MSL3 + 1000hr	0 / 47
INN3168C	M6T338A	E180601	MSL3 + 1000hr	0 / 47

THBT (Temperature Humidity Bias)

Product	Lot #	Qualification Project	Test Duration	No. Failures/Sample Size
INN3168C	M6P085B	E175001	MSL3 + 1000hr	0 / 47
INN3168C	M6P084B	E172011	MSL3 + 1000hr	0 / 47
INN3168C	M6T338A	E180601	MSL3 + 1000hr	0 / 47

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HTSL (High Temperature Storage Life)

Product	Lot #	Qualification Project	Test Duration	No. Failures/Sample Size
INN3168C	M6P085B	E175001	MSL3 + 1000hr	0 / 47
INN3168C	M6P084B	E172011	MSL3 + 1000hr	0 / 47
INN3168C	M6T338A	E180601	MSL3 + 1000hr	0 / 47

TMCL (Temperature Cycling)

Product	Lot #	Qualification Project	Test Duration	No. Failures/Sample Size
INN3168C	M6P085B	E175001	MSL3 + 850 cyc	0 / 47
INN3168C	M6P084B	E172011	MSL3 + 850 cyc	0 / 47
INN3168C	M6T338A	E180601	MSL3 + 850 cyc	0 / 47

HALT (Humidity Accelerated Life Test)

Product	Lot #	Qualification Project	Test Duration	No. Failures/Sample Size
INN3168C	M6P085B	E175001	MSL3 + 1000hr	0 / 20
INN3168C	M6P084B	E172011	MSL3 + 1000hr	0 / 20
INN3168C	M6T338A	E180601	MSL3 + 1000hr	0 / 20

Conclusion: Based on acceptable results, InnoSwitch-3 products are qualified for wafer fabrication at Japan Semiconductor Corporation ("JSO"), Oita, Japan.

CUSTOMER ACKNOWLEDGEMENT

Power Integrations requests you acknowledge the receipt of the above-mentioned PCN. If no acknowledgment is received within 30 days of this notification, Power Integrations will assume the change is acceptable. Lack of any additional response within 90 days of this notification further constitutes acceptance of the change.

Power Integrations reserves the right to ship either version manufactured after the effective date.

If you have any questions or need further assistance, please contact your regional Power Integrations sales office. Otherwise, please check the box below, acknowledging the receipt of the PCN.

The indicated Product/Process Change Notification was received by the undersigned authority.

Name/Title:	 	
Signature:		
Email Address/Phone#:	 	
Company/Location:	 	
CUSTOMER COMMENTS		

Please email this signed form to <u>pcn@power.com</u> specifying the PCN# in the subject.